

## 74V1G04

## SINGLE INVERTER

#### PRELIMINARY DATA

- HIGH SPEED: tpp = 3.8 ns (TYP.) at Vcc = 5V
- LOW POWER DISSIPATION:  $I_{CC} = 1 \mu A \text{ (MAX.)}$  at  $T_A = 25 \, ^{\circ}\text{C}$
- HIGH NOISE IMMUNITY: V<sub>NIH</sub> = V<sub>NIL</sub> = 28% V<sub>CC</sub> (MIN.)
- POWER DOWN PROTECTION ON INPUTS
- SYMMETRICAL OUTPUT IMPEDANCE: ||OH| = ||OL| = 8 mA (MIN)
- BALANCED PROPAGATION DELAYS: tplh ≅ tphl
- OPERATING VOLTAGE RANGE:
  V<sub>CC</sub> (OPR) = 2V to 5.5V
- IMPROVED LATCH-UP IMMUNITY

#### **DESCRIPTION**

The 74V1G04 is an advanced high-speed CMOS SINGLE INVERTER fabricated with sub-micron silicon gate and double-layer metal wiring C<sup>2</sup>MOS technology. It has similar high speed performance of equivalent Bipolar Schottky TTL combined with true CMOS low power dissipation.

The internal circuit is composed of 3 stages

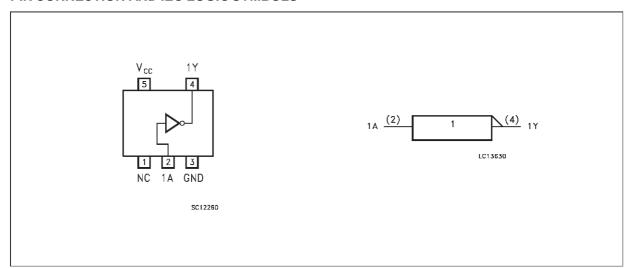


including buffer output, which provide high noise immunity and stable output.

Power down protection is provided on all inputs and 0 to 7V can be accepted on inputs with no regard to the supply voltage. This device can be used to interface 5V to 3V.

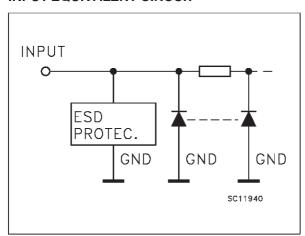
All inputs and outputs are equipped with protection circuits against static discharge, giving them 2KV ESD immunity and transient excess voltage.

#### PIN CONNECTION AND IEC LOGIC SYMBOLS



March 1998 1/6

## INPUT EQUIVALENT CIRCUIT



#### **PIN DESCRIPTION**

| PIN No | SYMBOL | NAME AND FUNCTION       |  |  |  |  |
|--------|--------|-------------------------|--|--|--|--|
| 1      | N.C.   | Not Connected           |  |  |  |  |
| 2      | 1A     | Data Input              |  |  |  |  |
| 4      | 1Y     | Data Output             |  |  |  |  |
| 3      | GND    | Ground (0V)             |  |  |  |  |
| 5      | Vcc    | Positive Supply Voltage |  |  |  |  |

### **TRUTH TABLE**

| Α | Υ |
|---|---|
| L | Н |
| Н | L |

## **ABSOLUTE MAXIMUM RATINGS**

| Symbol                  | Parameter                            | Value                         | Unit |
|-------------------------|--------------------------------------|-------------------------------|------|
| Vcc                     | Supply Voltage                       | -0.5 to +7.0                  | V    |
| Vı                      | DC Input Voltage                     | -0.5 to +7.0                  | V    |
| Vo                      | DC Output Voltage                    | -0.5 to V <sub>CC</sub> + 0.5 | V    |
| I <sub>IK</sub>         | DC Input Diode Current               | - 20                          | mA   |
| I <sub>OK</sub>         | DC Output Diode Current              | ± 20                          | mA   |
| lo                      | DC Output Current                    | ± 25                          | mA   |
| Icc or I <sub>GND</sub> | DC V <sub>CC</sub> or Ground Current | ± 50                          | mA   |
| T <sub>stg</sub>        | Storage Temperature                  | -65 to +150                   | °C   |
| TL                      | Lead Temperature (10 sec)            | 260                           | °C   |

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

### **RECOMMENDED OPERATING CONDITIONS**

| Symbol          | Parameter   | Value                | Unit         |
|-----------------|---|----------------------|--------------|
| Vcc             | Supply Voltage  | 2.0 to 5.5           | V            |
| VI              | Input Voltage   | 0 to 5.5             | V            |
| Vo              | Output Voltage  | 0 to V <sub>CC</sub> | V            |
| T <sub>op</sub> | Operating Temperature   | -40 to +85           | °C           |
| dt/dv           | Input Rise and Fall Time (see note 1) ( $V_{CC} = 3.3 \pm 0.3V$ ) ( $V_{CC} = 5.0 \pm 0.5V$ ) | 0 to 100<br>0 to 20  | ns/V<br>ns/V |

<sup>1)</sup> V<sub>IN</sub> from 30% to 70% of V<sub>CC</sub>

2/6

#### **DC SPECIFICATIONS**

| Symbol          | Parameter                   | Tes        | Test Conditions    |                        |                    | Value |                    |                    |                    | Unit |  |
|-----------------|-----------------------------|------------|--------------------|------------------------|--------------------|-------|--------------------|--------------------|--------------------|------|--|
|                 |                             | Vcc        |                    |                        | $T_A = 25$ °C      |       |                    | C.                 | -40 to 85 °C       |      |  |
|                 |                             | (V)        |                    |                        | Min.               | Тур.  | Max.               | Min.               | Max.               |      |  |
| V <sub>IH</sub> | High Level Input            | 2.0        |                    |                        | 1.5                |       |                    | 1.5                |                    | V    |  |
|                 | Voltage                     | 3.0 to 5.5 |                    |                        | 0.7V <sub>CC</sub> |       |                    | 0.7V <sub>CC</sub> |                    | V    |  |
| VIL             | Low Level Input             | 2.0        |                    |                        |                    |       | 0.5                |                    | 0.5                | V    |  |
|                 | Voltage                     | 3.0 to 5.5 |                    |                        |                    |       | 0.3V <sub>CC</sub> |                    | 0.3V <sub>CC</sub> | V    |  |
| VoH             | High Level Output           | 2.0        |                    | Ιο=-50 μΑ              | 1.9                | 2.0   |                    | 1.9                |                    |      |  |
|                 | Voltage                     | 3.0        | V1 =               | I <sub>O</sub> =-50 μA | 2.9                | 3.0   |                    | 2.9                |                    | .,   |  |
|                 |                             | 4.5        | V <sub>IL</sub>    | I <sub>O</sub> =-50 μA | 4.4                | 4.5   |                    | 4.4                |                    | V    |  |
|                 |                             | 3.0        |                    | I <sub>O</sub> =-4 mA  | 2.58               |       |                    | 2.48               |                    |      |  |
|                 |                             | 4.5        |                    | I <sub>O</sub> =-8 mA  | 3.94               |       |                    | 3.8                |                    |      |  |
| Vol             | Low Level Output            | 2.0        |                    | Ιο=50 μΑ               |                    | 0.0   | 0.1                |                    | 0.1                |      |  |
|                 | Voltage                     | 3.0        | V <sub>1</sub> =   | I <sub>O</sub> =50 μA  |                    | 0.0   | 0.1                |                    | 0.1                | V    |  |
|                 |                             | 4.5        | VIL                | Ιο=50 μΑ               |                    | 0.0   | 0.1                |                    | 0.1                | V    |  |
|                 |                             | 3.0        |                    | I <sub>O</sub> =4 mA   |                    |       | 0.36               |                    | 0.44               |      |  |
|                 |                             | 4.5        |                    | I <sub>O</sub> =8 mA   |                    |       | 0.36               |                    | 0.44               |      |  |
| II              | Input Leakage Current       | 0 to 5.5   | $V_1 = 5$ .        | 5V or GND              |                    |       | ±0.1               |                    | ±1.0               | μΑ   |  |
| Icc             | Quiescent Supply<br>Current | 5.5        | V <sub>I</sub> = V | cc or GND              |                    |       | 1                  |                    | 10                 | μΑ   |  |

## AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3 \text{ ns}$ )

| Symbol           | Parameter         | Test Condition      |                         | Value |          |      |        |       | Unit |
|------------------|-------------------|---------------------|-------------------------|-------|----------|------|--------|-------|------|
|                  |                   | Vcc                 |                         | T.    | A = 25 ° | C C  | -40 to | 85 °C |      |
|                  |                   | (V)                 |                         | Min.  | Тур.     | Max. | Min.   | Max.  |      |
| t <sub>PLH</sub> | Propagation Delay | 3.3 <sup>(*)</sup>  | $C_{L} = 15 pF$         |       | 5.0      | 7.0  | 1.0    | 8.5   |      |
| t <sub>PHL</sub> | Time              | 3.3 <sup>(*)</sup>  | $C_L = 50 pF$           |       | 7.5      | 10.0 | 1.0    | 12.0  | ns   |
|                  |                   | 5.0 <sup>(**)</sup> | $C_{L} = 15 \text{ pF}$ |       | 3.8      | 5.5  | 1.0    | 6.5   |      |
|                  |                   | 5.0 <sup>(**)</sup> | $C_L = 50 pF$           |       | 5.3      | 7.5  | 1.0    | 8.5   |      |

<sup>(\*)</sup> Voltage range is 3.3V ± 0.3V (\*\*) Voltage range is 5V ± 0.5V

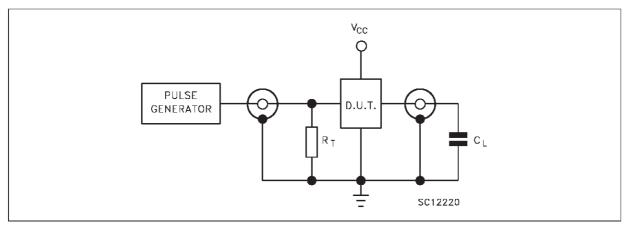
# CAPACITIVE CHARACTERISTICS

| Symbol          | Parameter                                 | Test Conditions | Value                  |      |              |      |      | Unit |
|-----------------|---|-----------------|------------------------|------|--------------|------|------|------|
|                 |   |                 | T <sub>A</sub> = 25 °C |      | -40 to 85 °C |      |      |      |
|                 |   |                 | Min.                   | Тур. | Max.         | Min. | Max. |      |
| C <sub>IN</sub> | Input Capacitance                         |                 |                        | 4    | 10           |      | 10   | pF   |
| C <sub>PD</sub> | Power Dissipation<br>Capacitance (note 1) |                 |                        | 18   |              |      |      | pF   |

<sup>1)</sup>  $C_{PD}$  is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation.  $I_{CC}(opr) = C_{PD} \bullet V_{CC} \bullet f_{IN} + I_{CC}/4$  (per Gate)



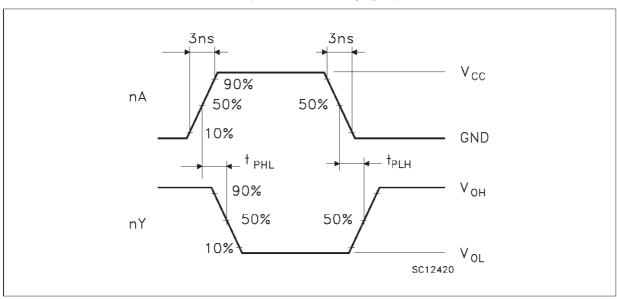
### **TEST CIRCUIT**



 $C_L = 15/50 \ pF$  or equivalent (includes jig and probe capacitance)

 $R_T = Z_{OUT}$  of pulse generator (typically  $50\Omega$ )

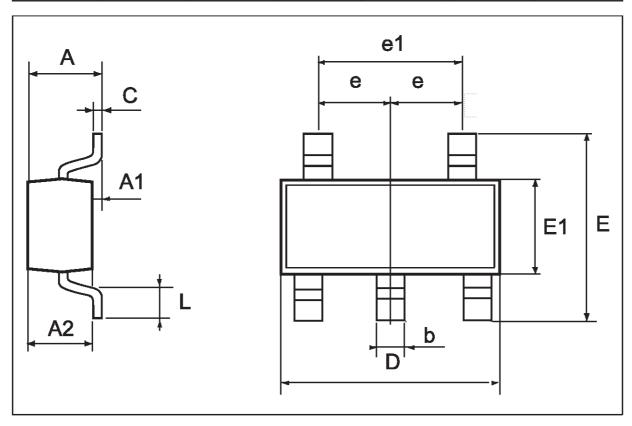
# WAVEFORM: PROPAGATION DELAYS (f=1MHz; 50% duty cycle)



4/6

## **SOT23-5L MECHANICAL DATA**

| DIM. |      | mm   |      | mils  |      |       |  |
|------|------|------|------|-------|------|-------|--|
|      | MIN. | TYP. | MAX. | MIN.  | TYP. | MAX.  |  |
| А    | 0.90 |      | 1.45 | 35.4  |      | 57.1  |  |
| A1   | 0.00 |      | 0.15 | 0.0   |      | 5.9   |  |
| A2   | 0.90 |      | 1.30 | 35.4  |      | 51.2  |  |
| b    | 0.35 |      | 0.50 | 13.7  |      | 19.7  |  |
| С    | 0.09 |      | 0.20 | 3.5   |      | 7.8   |  |
| D    | 2.80 |      | 3.00 | 110.2 |      | 118.1 |  |
| Е    | 2.60 |      | 3.00 | 102.3 |      | 118.1 |  |
| E1   | 1.50 |      | 1.75 | 59.0  |      | 68.8  |  |
| L    | 0.35 |      | 0.55 | 13.7  |      | 21.6  |  |
| е    |      | 0.95 |      |       | 37.4 |       |  |
| e1   |      | 1.9  |      |       | 74.8 |       |  |



**577** 

Information furnished is believed to be accurate and reliable. However, SGS-THOMSON Microelectronics assumes no responsability for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may results from its use. No license is granted by implication or otherwise under any patent or patent rights of SGS-THOMSON Microelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. SGS-THOMSON Microelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of SGS-THOMSON Microelectonics.

© 1998 SGS-THOMSON Microelectronics - Printed in Italy - All Rights Reserved

SGS-THOMSON Microelectronics GROUP OF COMPANIES

Australia - Brazil - Canada - China - France - Germany - Hong Kong - Italy - Japan - Korea - Malaysia - Malta - Morocco - The Netherlands - Singapore - Spain - Sweden - Switzerland - Taiwan - Thailand - United Kingdom - U.S.A

6/6